

12500 TI Boulevard, MS 8640, Dallas, Texas 75243

PCN# 20130903003
Qualification of ASESH, TITL and JCAP
as Additional Assembly and Test Site
for Select Devices
Change Notification / Sample Request

Date: 9/12/2013

To: Newark/Farnell PCN

Dear Customer:

This is an announcement of change to a device that is currently offered by Texas Instruments. The details of this change are on the following pages.

This notice does not change the end-of-life status of any product. Should product affected be on a previously issued product withdrawal/discontinuance notice, this notification does not extend the life of that product or change the life time buy offering/discontinuance plan.

We request you acknowledge receipt of this notification within **30** days of the date of this notice. If you require samples to conduct an evaluation, please make any request within the 30 days—samples are not built ahead of the change. Please see the schedule on the following pages for availability dates. You may contact the PCN Manager or your local Field Sales Representative to acknowledge this PCN and request samples.

The changes discussed within this PCN will not take effect any earlier than **90** days from the date of this notification, unless customer agreement has been reached on an earlier implementation of the change. This notification period is per TI's standard process. Any negotiated alternative change requirements will be provided via the customer's defined process. Customers with previously negotiated, special requirements will be handled separately. Any inquiries should be directed to your local Field Sales Representative.

For questions regarding this notice, contact your local Field Sales Representative or the PCN Manager (PCN www admin team@list.ti.com).

Sincerely,

PCN Team SC Business Services Phone: +1(214) 480-6037 Fax: +1(214) 480-6659

20130903003 Attachment: 1

Products Affected:

The devices listed on this page are a subset of the complete list of affected devices. According to our records, these are the devices that you have purchased within the past twenty-four (24) months. The corresponding customer part number is also listed, if available.

DEVICE	CUSTOMER PART NUMBER
OPA1632DGN	null
THS4131IDGN	null
CDC3RL02YFPR	null
THS3110IDGN	null
THS3121IDGN	null
THS3202DGK	null
THS3202DGN	null
THS4031IDGN	null
THS4121IDGK	null
THS4130IDGK	null
THS4130IDGNR	null
THS4222DGK	null
THS4504DGN	null
THS4505DGK	null
TPS22932BYFPT	null
THS3001IDGN	null
THS4131CDGN	null

Technical details of this Product Change follow on the next page(s).

PCN	Number: 20130903003 PCN Date: 09/12/201						/12/2013								
Title	Title: Qualification of ASESH, TITL and JCAP as Additional Assembly / Test Site for Select Devices						Select								
	stomer PCN_ww_admin_team@list.ti.com Phone: +1(214)480-6037					0-6037	De		Quality Services						
Prop	osed	1 st	Ship Date:		12/	12/2013	Esti	imated Sa	ample	A	vail	ability:			rovided at request
Char	nge Ty	/pe	:												
\boxtimes	Asse	mb	ly Site			Assembly	Prod	cess			\boxtimes	Assembly	Mate	erial	S
	Desi	_						cification				Mechanica		ecif	ication
	Test			ا	<u> </u>			ing/Labelii	าg		<u> </u>	Test Proc			
			Sump Site		<u> </u>	Wafer Bu	_				<u> </u>	Wafer Bur			
Ш	Wafe	er F	ab Site		<u> </u>	Wafer Fa						Wafer Fal	Pro	ces	S
					Ш	Part num	ber c	hange							
							PCN	N Details	5						
Desc	riptio	n c	of Change:												
differ	ences	ar	s are indicat e as follows ce: HNT to	:		_	es to	Product .	ldentif	ica	atioi	n" tables be	elow	. As	ssembly
	_						Н	TV				AS	ESH		
Wire	e type						1.0 №	1il Au				1.0 1	4il C	u	
Mole	d Com	ροι	ınd				450	179				EN20	0051	.5	
Grou	p 2 D	evi	ce: AMKOR	K1	to	TITL									
						Į.	AMKC	OR K1				T	TL		
Lead	d finis	h					Matt	e Sn				NiP	dAu		
Mole	d Com	ροι	ınd				L0131	L9570				420	5442	2	
Grou	Group 3 Device: STS to JCAP														
							STS					JCA			
Bur	np Sit	е					STS	S-BP				JCAF	P-FA	В	
Test coverage, insertions, conditions will remain consistent with current testing and verified with test MQ.															
Reas	on fo	r C	hange:												
Continuity of Supply															
Antic	cipate	d 1	impact on F	it,	Foi	rm, Funct	ion,	Quality o	r Relia	bi	lity	(Positive	/ Ne	egat	ive):
None															

Changes to Product Identification Resulting from this PCN:

Group 1 Device: HNT to ASESH

Assembly Site				
Hana Thailand	Assembly Site Origin (22L)	ASO: HNT		
ASE Shanghai	Assembly Site Origin (22L)	ASO: ASH		

ASSEMBLY SITE CODES: HNT =H, ASESH = A

Group 2 Device: AMKOR K1 to TITL

Assembly Site		
AMKOR Korea K1	Assembly Site Origin (22L)	ASO: AMN
TI Taiwan	Assembly Site Origin (22L)	ASO: TAI

ASSEMBLY SITE CODES: AMN =7, TITL = T

Group 3 Device: SCS to JCAP

Assembly Site		
STATS ChipPAC-AT	Assembly Site Origin (22L)	ASO: STS
JCAP-AT	Assembly Site Origin (22L)	ASO: JCP

ASSEMBLY SITE CODES: STS =G, JCAP = P

Sample product shipping label (not actual product label)

TEXAS INSTRUMENTS

MADE IN: Malaysia 2DC: 2Q:

MSL '2 /260C/1 YEAR SEAL DT MSL 1 /235C/UNLIM 03/29/04

OPT:

TTEM: 5A (L)TO:3750



(1P) \$N74L\$07N\$R (Q) 2000 (D) 0336 (31T)LOT: 3959047MLA (4W) TKY(1T) 7523483S12 (P) (2P) REV: (V) 0033317 (20L) CSO: SHE (21L) CCO:USA (22L) ASO: MLA (23L) ACO: MYS

Product Affected: Group 1 Device

OPA1632DGN	THS3202DGNG4	THS4121IDGN	THS4150CDGNG4
OPA1632DGNG4	THS3202DGNR	THS4121IDGNG4	THS4150CDGNR
OPA1632DGNR	THS3202DGNRG4	THS4121IDGNR	THS4150CDGNRG4
OPA1632DGNRG4	THS4011CDGN	THS4121IDGNRG4	THS4150IDGN
THS3001CDGN	THS4011CDGNG4	THS4130CDGK	THS4150IDGNG4
THS3001CDGNG4	THS4011CDGNR	THS4130CDGKG4	THS4150IDGNR
THS3001CDGNR	THS4011CDGNRG4	THS4130CDGN	THS4150IDGNRG4
THS3001CDGNRG4	THS4011IDGN	THS4130CDGNG4	THS4151CDGK
THS3001HVCDGN	THS4011IDGNG4	THS4130CDGNR	THS4151CDGKG4
THS3001HVCDGNG4	THS4011IDGNR	THS4130CDGNRG4	THS4211DGK
THS3001HVIDGN	THS4011IDGNRG4	THS4130IDGK	THS4211DGKG4
THS3001HVIDGNG4	THS4022IDGN	THS4130IDGKG4	THS4211DGN
THS3001IDGN	THS4022IDGNG4	THS4130IDGKR	THS4211DGNG4
THS3001IDGNG4	THS4022IDGNR	THS4130IDGKRG4	THS4211DGNR
THS3001IDGNR	THS4022IDGNRG4	THS4130IDGN	THS4211DGNRG4
THS3001IDGNRG4	THS4031CDGN	THS4130IDGNG4	THS4222DGK
THS3062DGN	THS4031CDGNG4	THS4130IDGNR	THS4222DGKG4
THS3062DGNG4	THS4031CDGNR	THS4130IDGNRG4	THS4222DGN
THS3110IDGN	THS4031CDGNRG4	THS4131CDGK	THS4222DGNG4
THS3110IDGNG4	THS4031IDGN	THS4131CDGKG4	THS4222DGNR

THS3110IDGNR	THS4031IDGNG4	THS4131CDGKR	THS4222DGNRG4		
THS3110IDGNRG4	THS4031IDGNR	THS4131CDGKRG4	THS4500IDGK		
THS3111CDGNR	THS4031IDGNRG4	THS4131CDGN	THS4500IDGKG4		
THS3111CDGNRG4	THS4032CDGN	THS4131CDGNG4	THS4500IDGN		
THS3111IDGN	THS4032CDGNG4	THS4131CDGNR	THS4500IDGNG4		
THS3111IDGNG4	THS4032IDGN	THS4131CDGNRG4	THS4500IDGNR		
THS3111IDGNR	THS4032IDGNG4	THS4131IDGK	THS4500IDGNRG4		
THS3111IDGNRG4	THS4032IDGNR	THS4131IDGKG4	THS4504DGK		
THS3120CDGN	THS4032IDGNRG4	THS4131IDGKR	THS4504DGKG4		
THS3120CDGNG4	THS4121CDGK	THS4131IDGKRG4	THS4504DGN		
THS3120CDGNR	THS4121CDGKG4	THS4131IDGN	THS4504DGNG4		
THS3120CDGNRG4	THS4121CDGKR	THS4131IDGNG4	THS4504DGNR		
THS3120IDGN	THS4121CDGKRG4	THS4131IDGNR	THS4504DGNRG4		
THS3120IDGNG4	THS4121CDGN	THS4131IDGNRG4	THS4505DGK		
THS3121IDGN	THS4121CDGNG4	THS4140CDGN	THS4505DGKG4		
THS3121IDGNG4	THS4121CDGNR	THS4140CDGNG4	THS4505DGN		
THS3202DGK	THS4121CDGNRG4	THS4140IDGN	THS4505DGNG4		
THS3202DGKG4	THS4121IDGK	THS4140IDGNG4	THS4505DGNR		
THS3202DGKR	THS4121IDGKG4	THS4140IDGNR	THS4505DGNRG4		
THS3202DGKRG4	THS4121IDGKR	THS4140IDGNRG4	THS6072IDGNR		
THS3202DGN	THS4121IDGKRG4	THS4150CDGN	THS6072IDGNRG4		
Product Affected, Group 2 Device					

Product Affected: Group 2 Device

MSP430V250IPZ

Product Affected: Group 3 Device

CDC3RL02YFPR TPS22932BYFPR TPS22932BYFPT

Qualification Data: Group 1

This qualification has been specifically developed for the validation of this change. The qualification data validates that the proposed change meets the applicable released technical specifications.

Qual Vehicle: THS3202DGK (MSL1-260C)

Package Construction Details

i ackage construction betains						
Assembly Site:	ASESH	Mold Compound:	EN2000515			
# Pins-Designator, Family:	8-DGK, MSOP	Mount Compound:	EY1000063			
Lead Finish, Base	NiPdAu, Cu	Bond Wire:	1.0 Mil Dia. Cu			

Qualification: Plan Test Results

Reliability Test	Conditions	Sample Size / Fail			
Electrical Characterization	-	Pass			
**Temperature Cycle	-65C/+150C (500 Cyc)	77/0			
Manufacturability (MQ)	(per mfg. Site specification)	Pass			
Moisture Sensitivity L1-260C 12/0					
Notes **- Preconditioning sequence: Level 1-260C.					

Reference Qualification	1						
_	al Vehicle : LM358AD0	KR (MSL1-260C)					
Package Construction Details							
Assembly Site:	ASESH	Mold Comp	ound:				
# Pins-Designator, Family:	8-DGK, MSOP	Mount Comp	ound:	EY1000063			
Lead Finish, Base	NiPdAu, Cu	Bond	Wire:	1.0 Mil Dia.	Cu		
Qualification: Plan	Test Results	1	<u>'</u>				
Reliability Test	Conditions		Sa	ample Size /	Fail		
			Lot#	1 Lot#2	Lot#3		
**Steady-state Life Test	150C (168 Hour	rs)	77/0	77/0	77/0		
**High Temp. Storage Bake	150C (500 Hour	'S)	77/0	77/0	77/0		
**Biased HAST	130C/85%RH (9	96 Hours)	77/0	77/0	77/0		
**Autoclave 121C	121C, 2 atm (9		77/0	77/0	77/0		
**Temperature Cycle	-65C/+150C (5	00 Cyc)	77/0	77/0	77/0		
Solderability	Steam age, 8 H	lours	22/0	22/0	22/0		
Flammability	Method A - ULS	94-0	5/0	5/0	5/0		
Flammability	Method B - IEC	695-2-2	5/0	5/0	5/0		
Flammability	Method C - UL	1694	5/0	5/0	5/0		
Salt Atmosphere	24 Hours	24 Hours			5/0		
Manufacturability (MQ)	(per mfg. Site s	(per mfg. Site specification)			Pass		
Moisture Sensitivity	L1-260C				12/0		
Notes **- Preconditioning se	equence: Level 1-260C.						
	Qualification Dat						
This qualification has been speci validates that the proposed cha					on data		
Qual	Vehicle: MSP430F479	94IPZ (MSL1-2600					
	Package Construct	tion Details					
Assembly Site:	TITL	Mold Comp	4205442				
# Pins-Designator, Family:	100-PZ, LQFP	Mount Comp	ound:				
Lead Finish, Base	NiPdAu, Cu	Bond	Wire:	0.95 Mil Dia	. Au		
Qualification: \square Plan \boxtimes	Test Results	-	<u>'</u>				
Reliability Test	Conditions		Sa	ample Size /	Fail		
Electrical Characterization	-		Pass				
**Operating Life Test	150C (300 Hou	150C (300 Hours)			120/0		
**Temperature Cycle	-65C/+150C (1	-65C/+150C (1000 Cyc)			77/0		
**High Temp. Storage Bake		170C (420 Hours)			77/0		
ESD CDM	+/-500V	+/-500V			3/0		
ESD HBM	+/-2KV			3/0			
ESD MM	+/-500V						
X-ray	Top side only	-			3/0 5/0		
Manufacturability (MQ) (per mfg. Site specification) Pass							
Notes **- Preconditioning sequence: Level 1-260C.							

Qualification Data: Group 3					
This qualification has been specifically developed for the validation of this change. The qualification data validates that the proposed change meets the applicable released technical specifications.					
Qual V	ehicle: CD3239	(MSL1-260C)			
Pac	kage Construct	ion Details			
Assembly & Bump Site: JCAP		Bump Compos	sition:	SnAgCu	
# Pins-Designator, Family: 25-YF	P, WCSP	Bump Dian	neter:	0.23mm	
Qualification: Plan Test Results					
Reliability Test	Conditions		Sa	mple Size /	Fail
			Lot#1	Lot#2	Lot#3
**Steady-state Life Test	150C (300 Hour	s)	116/0	116/0	116/0
**High Temp. Storage Bake	150C (1000 Hou	ırs)	77/0	77/0	77/0
**Biased HAST	130C/85%RH (9	6 Hours)	77/0	77/0	77/0
**Unbiased HAST	130C/85%RH (9	6 Hours)	77/0	77/0	77/0
**Temperature Cycle	-55C/+125C (10	000 Cyc)	77/0	77/0	77/0
Manufacturability (MQ)	(per mfg. Site s	pecification)	Pass	Pass	Pass
Moisture Sensitivity	L1-260C		12/0	12/0	12/0
Notes **- Preconditioning sequence: Level 1-260C.					

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
Japan	PCNJapanContact@list.ti.com